

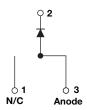
RoHS

HALOGEN FREE

HEXFRED® Ultrafast Soft Recovery Diode, 16 A



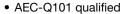
D²PAK

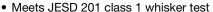


PRODUCT SUMMARY								
Package	TO-263AB (D ² PAK)							
I _{F(AV)}	16 A							
V_{R}	1200 V							
V _F at I _F	3.0 V							
t _{rr} (typ.)	30 ns							
T _J max.	150 °C							
Diode variation	Single die							

FEATURES

- Ultrafast and ultrasoft recovery
- Very low I_{RRM} and Q_{rr}
- · Specified at operating conditions
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C







BENEFITS

- Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

DESCRIPTION

VS-HFA16TB120SHM3 is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 1200 V and 16 A continuous current, the VS-HFA16TB120SHM3 is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (IRRM) and does not exhibit any tendency to "snap-off" during the t_b portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA16TB120SHM3 is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS				
Cathode to anode voltage	V_R		1200	V				
Maximum continuous forward current	I _F	T _C = 100 °C	16					
Single pulse forward current	I _{FSM}		190	Α				
Maximum repetitive forward current	I _{FRM}		64					
Maniana		T _C = 25 °C 151		10/				
Maximum power dissipation	P _D	T _C = 100 °C	60	W				
Operating junction and storage temperature range	T _J , T _{Stg}		-55 to +150	°C				

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ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA	1200	-	-				
Maximum forward voltage		I _F = 16 A		-	2.5	3.0	V		
	V_{FM}	I _F = 32 A	See fig. 1	-	3.2	3.93			
		I _F = 16 A, T _J = 125 °C		-	2.3	2.7			
Maximum reverse		V _R = V _R rated	= V _R rated		0.75	20			
leakage current	I _{RM}	$T_J = 125 ^{\circ}\text{C}, V_R = 0.8 \text{x} V_R \text{rated}$	See fig. 2	-	375	2000	μA		
Junction capacitance	C _T	V _R = 200 V See fig. 3		-	27	40	pF		
Series inductance	L _S	Measured lead to lead 5 mm from p	-	8.0	-	nΗ			

DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS		
Reverse recovery time See fig. 5 and 10	t _{rr}	$I_F = 1.0 \text{ A}, dI_F/dt = 200 \text{ A}$	-	30	-				
	t _{rr1}	T _J = 25 °C		-	90	-	ns A		
	t _{rr2}	T _J = 125 °C] , ,,,,	-	164	-			
Peak recovery current	I _{RRM1}	T _J = 25 °C	I _F = 16 A dI _F /dt = 200 A/μs V _B = 200 V	-	5.8	-			
See fig. 6	I _{RRM2}	T _J = 125 °C		-	8.3	-			
Reverse recovery charge See fig. 7	Q _{rr1}	T _J = 25 °C	7 VH - 200 V	-	260	-			
	Q _{rr2}	T _J = 125 °C		-	680	-	110		

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s	=	-	300	°C			
Thermal resistance, junction to case	R _{thJC}		-	-	0.83	K/W			
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	80	N VV			
Weight			-	2.0	-	g			
vveigni			-	0.07	-	OZ.			
Marking device		Case style D ² PAK		HFA16T	B120SH	•			

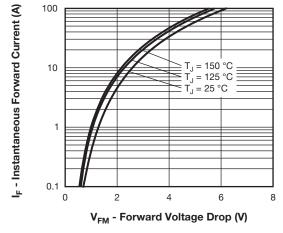


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current (Per Leg)

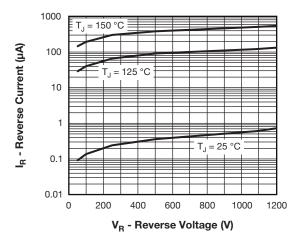


Fig. 2 - Typical Reverse Current vs. Reverse Voltage (Per Leg)

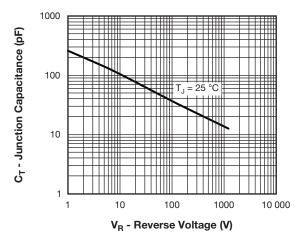


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

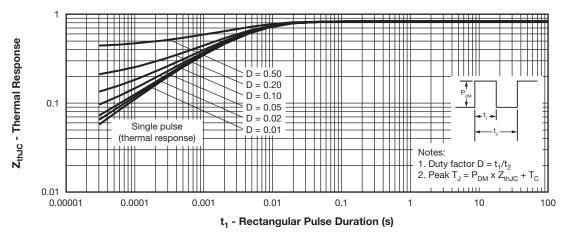


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

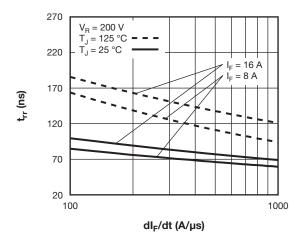


Fig. 5 - Typical Reverse Recovery Time vs. dl_F/dt (Per Leg)

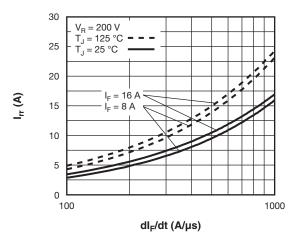


Fig. 6 - Typical Recovery Current vs. dI_F/dt (Per Leg)

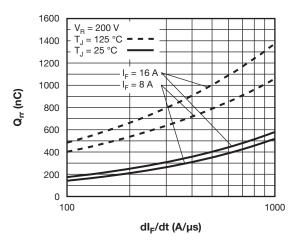
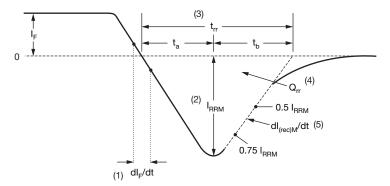


Fig. 7 - Typical Stored Charge vs. dl_F/dt (Per Leg)



- (1) dl_F/dt rate of change of current through zero crossing
- (2) $\boldsymbol{I}_{\text{RRM}}$ peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) $\mathbf{Q}_{\rm rr}$ area under curve defined by $\mathbf{t}_{\rm rr}$ and $\mathbf{I}_{\rm RRM}$

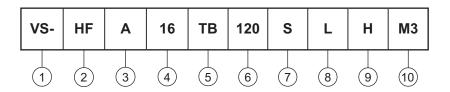
$$Q_{rr} = \frac{t_{rr} x I_{RRM}}{2}$$

(5) dl_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 8 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - HEXFRED® family

Process designator: A = Electron irradiated

Current rating (16 = 16 A)

5 - Package outline (TB = TO-220, 2 leads)

6 - Voltage rating (120 = 1200 V)

7 - $S = D^2PAK$

8 - • None = Tube

• L = tape and reel (left oriented)

• R = tape and reel (right oriented)

9 - H = AEC-Q101 qualified

- M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

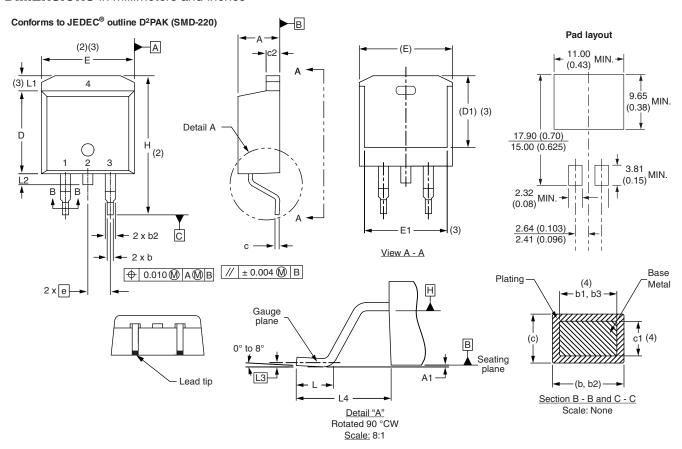
LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95046					
Part marking information	www.vishay.com/doc?95444					
Packaging information	www.vishay.com/doc?95032					

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-HFA16TB120SHM3	50	1000	Antistatic plastic tube						
VS-HFA16TB120SRHM3	800	800	13" diameter reel						
VS-HFA16TB120SLHM3	800	800	13" diameter reel						



D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	2.54 BSC 0.100 BSC			
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



Vishay

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